TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

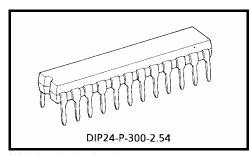
# TC74HC154AP

#### 4-to-16 Line Decoder

The TC74HC154A is a high speed CMOS 4 to 16 LINE DECODER/DEMULTIPLEXER fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

A binary code applied to the four inputs A thru D is decoded within the device. Depending on the binary code, causes one of sixteen outputs to go low, when both the strobe inputs,  $\overline{G}1$  and  $\overline{G}2$ , are held low. When either strobe input is held high, the decoding function is inhibited to keep all outputs high. The strobe function makes it easy to expand the decoding lines through cascading, and simplifies the design of address decoding circuits in a memory control system.



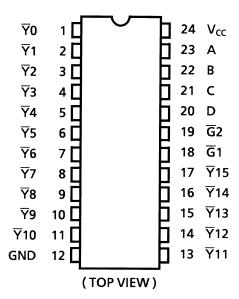
Weight: 1.50 g (typ.)

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

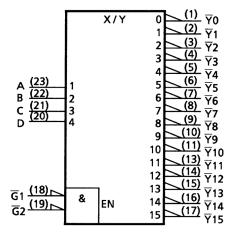
#### **Features**

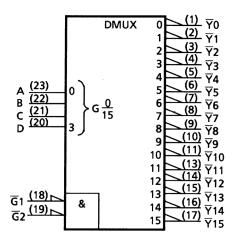
- High speed:  $t_{pd} = 15 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2~6 V
- Pin and function compatible with 74LS154

#### **Pin Assignment**



# **IEC Logic Symbol**





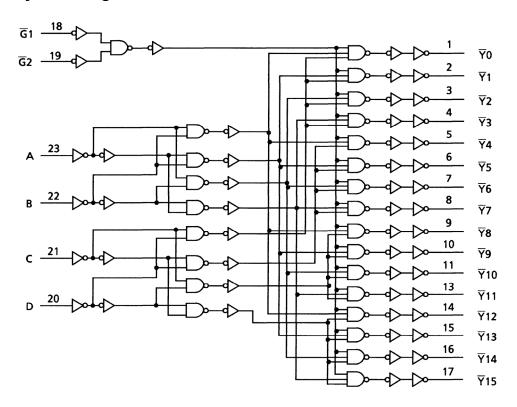
### **Truth Table**

		Selected				
 G1	G2	D	uts C	В	Α	Output (L)
L	L	L	L	L	L	<del>V</del> 0
L	L	L	L	L	Н	<u></u> Y 1
L	L	L	L	Н	L	<del>Y</del> 2
L	L	L	L	Н	Н	<del>Y</del> 3
L	L	L	Н	L	L	<del>Y</del> 4
L	L	L	Н	L	Н	<del>Y</del> 5
L	L	L	Н	Н	L	<del>Y</del> 6
L	L	L	Н	Н	Н	<del>Y</del> 7
L	L	Н	L	L	L	<del>-</del> 78
L	L	Н	L	L	Н	<del>7</del> 9
L	L	Н	L	Н	L	<del>Y</del> 10
L	L	Н	L	Н	Н	<u>₹</u> 11
L	L	Н	Н	L	L	<del>Y</del> 12
L	L	Н	Н	L	Н	<del>Y</del> 13
L	L	Н	Н	Н	L	<del>Y</del> 14
L	L	Н	Н	Н	Н	<del>Y</del> 15
Х	Н	Х	Х	Х	Х	None
Н	Х	Х	Х	Х	Х	None

X: Don't care

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### **System Diagram**



### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7	V
DC input voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> + 0.5	V
DC output voltage	Vout	-0.5~V <sub>CC</sub> + 0.5	٧
Input diode current	Ιικ	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	500 (Note 2)	mW
Storage temperature	T <sub>stg</sub>	−65 <b>~</b> 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of  $Ta = -40^{\circ}C \sim 65^{\circ}C$ . From  $Ta = 65^{\circ}C$  to  $85^{\circ}C$  a derating factor of -10 mW/°C shall be applied until 300 mW.

# **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2~6	V
Input voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
		0~1000 (V <sub>CC</sub> = 2.0 V)	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0~500 (V <sub>CC</sub> = 4.5 V)	ns
		0~400 (V <sub>CC</sub> = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Cumbal	Test Condition V <sub>CC</sub> (V)		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics	Symbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	$V_{IH}$			4.5	3.15	_	_	3.15	_	V
Ŭ				6.0	4.20	_	_	4.20		
					_	_	0.50	_	0.50	
Low-level input voltage	$V_{IL}$	_		4.5	_	_	1.35	_	1.35	V
				6.0	_	_	1.80	_	1.80	
	V <sub>ОН</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63		
	V <sub>OL</sub>	VIN = VIH or VIL		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			I <sub>OL</sub> = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	4.0	_	40.0	μА



# AC Characteristics (C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, Ta = 25°C, input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub>			4	8	ns
Output transition time	$t_{THL}$	_		7		115
Propagation delay time	t <sub>pLH</sub>			15	30	20
$(A, B, C, D-\overline{Y})$	$t_{pHL}$	_	_	15	30	ns
Propagation delay time	t <sub>pLH</sub>			4.4	20	
$(\overline{G}1, \overline{G}2-\overline{Y})$	t <sub>pHL</sub>	_	_	14	28	ns

## AC Characteristics ( $C_L = 50 \text{ pF}$ , input: $t_r = t_f = 6 \text{ ns}$ )

		Test Condition		Ta = 25°C		Ta = -4			
Characteristics	Symbol		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
	<b>4</b> —		2.0	_	30	75	_	95	
Output transition time	t <sub>TLH</sub>	_	4.5	_	8	15	_	19	ns
	t <sub>THL</sub>		6.0	_	7	13	_	16	
Propagation delay	4		2.0	_	65	175	_	220	
time	t <sub>pLH</sub>	_	4.5	_	19	35	_	44	ns
$(A, B, C, D-\overline{Y})$	t <sub>pHL</sub>		6.0	_	16	30	_	37	
Propagation delay	<b>4</b>		2.0	_	55	160	_	200	
time	t <sub>pLH</sub>	_	4.5	_	17	32	_	40	ns
$(\overline{G}1, \overline{G}2 - \overline{Y})$	t <sub>pHL</sub>		6.0	_	15	27	_	34	
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	57	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

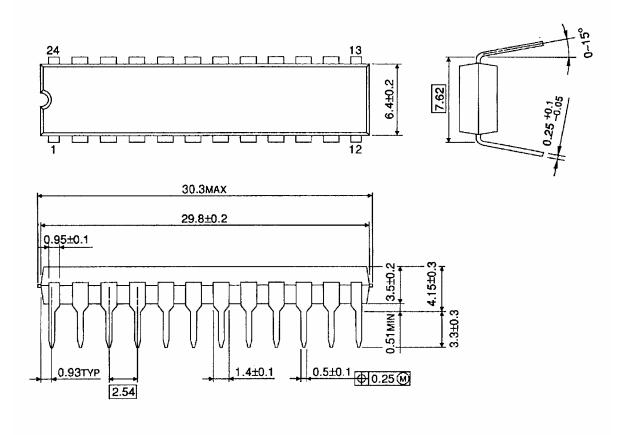
Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

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# **Package Dimensions**

DIP24-P-300-2.54 Unit: mm



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Weight: 1.50 g (typ.)

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20070701-EN GENERAL

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